NSN 5961-01-368-1252

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View Online at https://aerobasegroup.com/nsn/5961-01-368-1252 **Inclosure Material:** Metal **Overall Height:** 0.175 inches **Overall Width:** 0.290 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Thready Qty Per Inch (tpi): **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 collector to base voltage/static/emitter open and 20.0 collector to emitter voltage/static/base open and 3.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 200.00 milliamperes all primaries **Power Rating Per Characteristic:** 5.0 watts any acceptable absolute **Transfer Ratio:** 300.0 small-signal short-circuit forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unc **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life:

Demilitarization:

Unit Of Measure:

No

N/a

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